

Bidirectional TVS Diodes

DESCRIPTION

The SDxxC Series is designed for applications transient overvoltage requiring protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

This series has been specifically designed to protect sensitive components which are connected to power, data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events), and EFT (electrical fast transients).

FEATURES

- ♦I IEC61000-4-2 (ESD) ±30kV (Contact)
 - ±30kV (Air)
- ♦IEC61000-4-4 (EFT) 40A (5/50ns)
- ♦350 Watts Peak Pulse Power per (tp=8/20µs)
- ♦Protects one I/O line (bidirectional)
- ♦Low clamping voltage
- ♦ Working voltages: 3V,5V,8V,12V,15V,18V,20V,24V,36V
- ♦Low leakage current

MACHANICAL DATA

- ♦SOD-323 package
- →Flammability Rating: UL 94V-0
- ♦Packaging: Tape and Reel
- ♦ High temperature soldering guaranteed: 260 °C/10s
- ♦Reel size: 7 inch
- ♦MSL 1

ORDERING INFORMATION

Device: SDxxCPackage: SOD-323

♦ Material: Halogen free and RoHS compliant

♦ Packing: Tape & Reel
♦ Quantity per reel: 3,000pcs

APPLICATIONS

- ♦ Cell Phone Handsets and Accessories
- ♦ Microprocessor based equipment
- ♦ Personal Digital Assistants (PDA's)
- ♦ Notebooks, Desktops, and Servers
- ♦ Portable Instrumentation
- ♦ Networking and Telecom
- ♦ Serial and Parallel Ports.
- ♦Peripherals

PIN CONFIGURATION





PACKAGE OUTLINE





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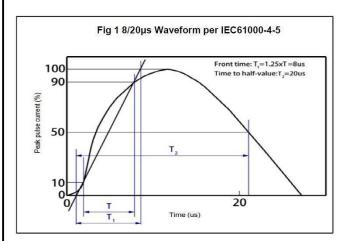
ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V _{ESD}	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±30 ±30	kV				
P _{PP}	Peak Pulse Power (8/20μs)	350	W				
Торт	Operating Temperature	-55/+150	°C				
T _{STG}	Storage Temperature	-55/+150	°C				
TL	Lead Soldering Temperature	260 (10 sec.)	°C				

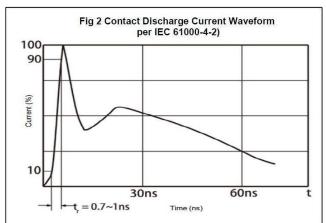
ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
PART NUMBER	DEVICE MARKING	V _{RWM} (V) (max.)	V _B (V) (min.)	I _T (mA)	V _C @1A (V) (max.)		/c /) (@A)	I _R (μΑ) (max.)	C _T (pF) (max.)
SD03C	2A	3.3	4.0	1	7.5	16.0	20	40	450
SD05C	2B	5.0	6.0	1	9.8	18.0	17	10	200
SD08C	2C	8.0	8.5	1	13.4	24.0	15	2	120
SD12C	2D	12.0	13.3	1	19.0	32.0	11	1	75
SD15C	2J	15.0	16.7	1	24.0	38.0	10	1	68
SD18C	2K	18.0	20.0	1	29.0	45.0	9	1	57
SD20C	2L	20.0	22.3	1	35.0	50.0	8	1	52
SD24C	2H	24.0	26.7	1	43.0	52.0	7	1	50
SD36C	2N	36.0	40.0	1	60.0	75.0	4.5	1	35

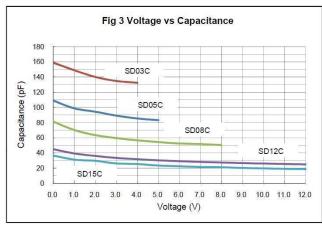


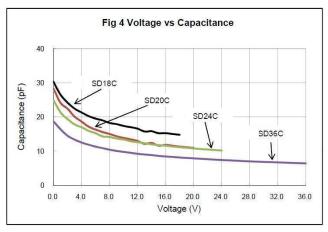
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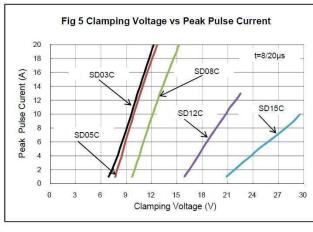
ELECTRICAL CHARACTERISTICS CURVE

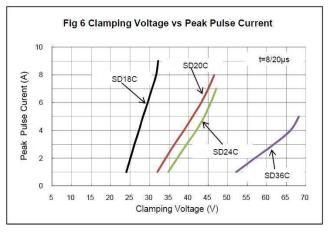








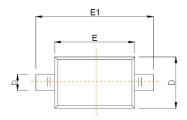


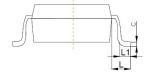


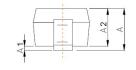


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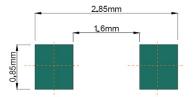
SOD-323 PACKAGE OUTLINE DIMENSIONS







Cymphol	Dimensions In Millimeters				
Symbol	Min	Max			
Α		1.00			
A1	0.000	0.100			
A2	0.800	0.900			
b	0.250	0.350			
С	0.080	0.150			
D	1.200	1.400			
E	1.600	1.800			
E1	2.500	2.700			
е	1.800	2.040			
L	0.475 REF				
L1	0.250	0.400			
θ	0°	8°			



Recommended Pad outline

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